CGY1041

1 GHz, 21 dB gain GaAs push-pull amplifier Rev. 1 — 10 February 2011

Product data sheet

Product profile 1.

1.1 General description

Hybrid amplifier module in a SOT115J package, operating at a supply voltage of 24 V Direct Current (DC), employing Heterojunction Field Effect Transistor (HFET) GaAs dies.

1.2 Features and benefits

- Excellent linearity, stability and reliability
- Extremely low noise
- Excellent return loss properties
- Rugged construction
- Unconditionally stable
- Thermally optimized design
- Superior levels of ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)
- Integrated ring wave surge protection
- Power gain is specified for both 870 MHz and 1003 MHz bandwidth

1.3 Applications

CATV systems operating in the 40 MHz to 1003 MHz frequency range

1.4 Quick reference data

Quick reference data

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \text{ V (DC)}$; $Z_S = Z_L = 75 \Omega$; $T_{mb} = 35 \text{ °C}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G_p	power gain	f = 45 MHz	19.0	20.0	21.0	dB
		f = 870 MHz	20.4	21.4	22.4	dB
		f = 1003 MHz	21.0	21.75	22.5	dB
СТВ	composite triple beat	$V_0 = 44 \text{ dBmV}$	<u>[1]</u> -	-62	-	dBc
CCN	carrier-to-composite noise	$V_0 = 44 \text{ dBmV}$	<u>[1]</u> -	63	-	dBc
I _{tot}	total current		[2] _	265	280	mA

^{[1] 79} NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat output level.



^[2] Direct Current (DC).

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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline Graphic symbol
1	input	
2, 3	common	1 3 5 7 9
5	+V _B	
7, 8	common	12/3/7/8
9	output	sym095
		7 ····

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
CGY1041	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{B}	supply voltage			-	30	V
$V_{i(RF)}$	RF input voltage	single tone		-	75	dBmV
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); According JEDEC standard 22-A114E	<u>[1]</u>	-	2000	V
		Biased; According IEC61000-4-2		-	2000	V
T _{stg}	storage temperature			-40	+100	°C
T_{mb}	mounting base temperature			-20	+100	°C

^[1] The value of 2000 V corresponds to a class 2 classification.

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5. Characteristics

Table 5. Characteristics

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \text{ V (DC)}$; $Z_S = Z_L = 75 \Omega$; $T_{mb} = 35 \degree \text{C}$; unless otherwise specified.

<u> </u>	19.0 20.4 21.0 1.2 - 20 19	20.0 21.4 21.75 1.95	21.0 22.4 22.5 2.7	dB dB dB
SL _{sl} slope straight line f = 45 MHz to 1003 MHz 12 FL flatness of frequency response f = 45 MHz to 1003 MHz 12 RL _{in} input return loss f = 45 MHz to 200 MHz f = 200 MHz to 550 MHz f = 870 MHz to 870 MHz f = 870 MHz to 1003 MHz f = 914 MHz to 1003 MHz RL _{out} output return loss f = 45 MHz to 200 MHz f = 200 MHz to 550 MHz f = 550 MHz to 550 MHz f = 550 MHz to 870 MHz	21.0 1.2 - 20 19	21.75 1.95	22.5	
SL _{sl} slope straight line f = 45 MHz to 1003 MHz I1 FL flatness of frequency response f = 45 MHz to 1003 MHz I2 RL _{in} input return loss f = 45 MHz to 200 MHz f = 200 MHz to 550 MHz f = 550 MHz to 914 MHz f = 914 MHz to 1003 MHz f = 45 MHz to 200 MHz RL _{out} output return loss f = 45 MHz to 200 MHz f = 200 MHz to 550 MHz f = 550 MHz to 870 MHz	1.2 - 20 19	1.95		dB
FL flatness of frequency response f = 45 MHz to 1003 MHz RLin input return loss f = 45 MHz to 200 MHz f = 200 MHz to 550 MHz f = 550 MHz to 870 MHz f = 870 MHz to 914 MHz f = 914 MHz to 1003 MHz RLout output return loss f = 45 MHz to 200 MHz f = 200 MHz to 550 MHz f = 550 MHz to 550 MHz f = 550 MHz to 870 MHz	20		2.7	
RLin input return loss	20 19	-	2.1	dB
$f = 200 \text{ MHz to } 550 \text{ MHz}$ $f = 550 \text{ MHz to } 870 \text{ MHz}$ $f = 870 \text{ MHz to } 914 \text{ MHz}$ $f = 914 \text{ MHz to } 1003 \text{ MHz}$ $RL_{out} \qquad \text{output return loss}$ $f = 45 \text{ MHz to } 200 \text{ MHz}$ $f = 200 \text{ MHz to } 550 \text{ MHz}$ $f = 550 \text{ MHz to } 870 \text{ MHz}$	19		0.9	dB
$f = 550 \text{ MHz to } 870 \text{ MHz}$ $f = 870 \text{ MHz to } 914 \text{ MHz}$ $f = 914 \text{ MHz to } 1003 \text{ MHz}$ $RL_{out} \qquad \text{output return loss} \qquad \qquad f = 45 \text{ MHz to } 200 \text{ MHz}$ $f = 200 \text{ MHz to } 550 \text{ MHz}$ $f = 550 \text{ MHz to } 870 \text{ MHz}$		-	-	dB
$f = 870 \text{ MHz to } 914 \text{ MHz}$ $f = 914 \text{ MHz to } 1003 \text{ MHz}$ $RL_{out} \qquad \text{output return loss} \qquad \qquad f = 45 \text{ MHz to } 200 \text{ MHz}$ $f = 200 \text{ MHz to } 550 \text{ MHz}$ $f = 550 \text{ MHz to } 870 \text{ MHz}$	10	-	-	dB
$f = 914 \text{ MHz to } 1003 \text{ MHz}$ $RL_{out} \text{output return loss} \qquad \qquad f = 45 \text{ MHz to } 200 \text{ MHz}$ $f = 200 \text{ MHz to } 550 \text{ MHz}$ $f = 550 \text{ MHz to } 870 \text{ MHz}$	13	-	-	dB
RL _{out} output return loss $ f = 45 \text{ MHz to } 200 \text{ MHz} $ $ f = 200 \text{ MHz to } 550 \text{ MHz} $ $ f = 550 \text{ MHz to } 870 \text{ MHz} $	19	-	-	dB
f = 200 MHz to 550 MHz f = 550 MHz to 870 MHz	16	-	-	dB
f = 550 MHz to 870 MHz	18	-	-	dB
	18	-	-	dB
f = 870 MHz to 914 MHz	18	-	-	dB
	18	-	-	dB
f = 914 MHz to 1003 MHz	16	-	-	dB
NF noise figure $f = 50 \text{ MHz}$ to 870 MHz	-	3.6	4.0	dB
f = 870 MHz to 1003 MHz	-	4.3	4.9	dB
I _{tot} total current [3	-	265	280	mΑ
79 NTSC channels + 75 digital channels				
CTB composite triple beat $V_o = 44 \text{ dBmV}$	-	-62	-	dBc
CSO composite second-order distortion $V_o = 44 \text{ dBmV}$	-	-64	-	dBc
Xmod cross modulation $V_o = 44 \text{ dBmV}$	-	-58	-	dB
CCN carrier-to-composite noise $V_o = 44 \text{ dBmV}$	-	63	-	dBc
79 NTSC channels				
CTB composite triple beat $V_o = 44 \text{ dBmV}$	-	-	-62	dBc
CSO composite second-order distortion V _o = 44 dBmV	-	-	-62	dBc
Xmod cross modulation $V_o = 44 \text{ dBmV}$	-	-58	-	dB
98 PAL channels				
CTB composite triple beat $V_0 = 44 \text{ dBmV}$		-68	-	dBc
CSO composite second-order distortion $V_0 = 44 \text{ dBmV}$	-	- •		
Xmod cross modulation $V_0 = 44 \text{ dBmV}$	-	-66	-	dBc

^[1] G_p at 1003 MHz minus G_p at 45 MHz.

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^[2] Flatness is defined as maximum deviation to straight line.

^[3] Direct Current (DC).

^{[4] 79} NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat output level.

^{[5] 79} NTSC channels [f = 55.25 MHz to 550 MHz]; flat output level.

^{[6] 98} PAL channels [f = 49.75 MHz to 847.25 MHz]; flat output level.

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6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J

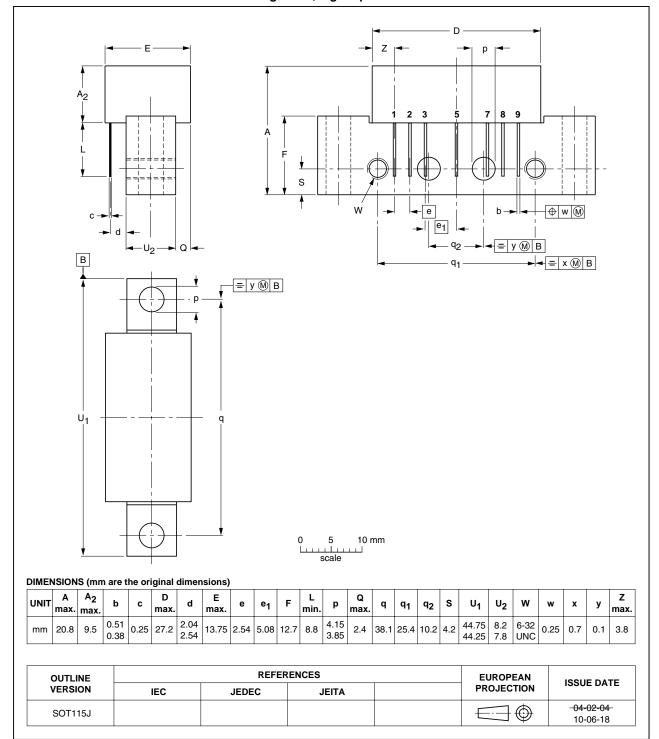


Fig 1. Package outline SOT115J

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7. Abbreviations

Table 6. Abbreviations

Acronym	Description
CATV	Community Antenna TeleVision
ESD	ElectroStatic Discharge
GaAs	Gallium Arsenide
NTSC	National Television Standard Committee
PAL	Phase Alternating Line
RF	Radio Frequency
UNC	UNified Coarse

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
CGY1041 v.1	20110210	Product data sheet	-	-

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9. Legal information

9.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Date of release: 10 February 2011 Document identifier: CGY1041